## Liang Zhao

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/5968422/publications.pdf Version: 2024-02-01

16 papers citations 1478505 6 1474206

16	322	6	9
papers	citations	h-index	g-index
16	16	16	462
all docs	docs citations	times ranked	citing authors

#	Article	IF	CITATIONS
1	High temperature characteristics of monolithically integrated LED and MOSâ€channel HEMT in GaN using selective epi removal. Physica Status Solidi (A) Applications and Materials Science, 2015, 212, 1110-1115.	1.8	19
2	High 400 °C operation temperature blue spectrum concentration solar junction in GalnN/GaN. Applied Physics Letters, 2014, 105, .	3.3	14
3	HOW DO WE LOSE EXCITATION IN THE GREEN?. , 2013, , .		0
4	Evaluation of metal/indium-tin-oxide for transparent low-resistance contacts to p-type GaN. Applied Optics, 2012, 51, 5596.	1.8	14
5	a-Plane GaN light emitting diodes on self-assembled Ni nano-islands. , 2012, , .		0
6	Fish scale terrace GalnN/GaN light-emitting diodes with enhanced light extraction. Applied Physics Letters, 2012, 101, 232106.	3.3	0
7	GaN-based light emitting diode with embedded SiO <inf>2</inf> pattern for enhanced light extraction. , 2012, , .		1
8	Defect-reduced green GaInN/GaN light-emitting diode on nanopatterned sapphire. Applied Physics Letters, 2011, 98, .	3.3	186
9	Non-polar GainN-based light-emitting diodes: an approach for wavelength-stable and polarized-light emitters. , 2011, , .		2
10	Photocurrent spectroscopy on GaInN/GaN multiple quantum well solar cell structures. Physica Status Solidi C: Current Topics in Solid State Physics, 2011, 8, 2469-2472.	0.8	0
11	HOW DO WE LOSE EXCITATION IN THE GREEN?. International Journal of High Speed Electronics and Systems, 2011, 20, 13-25.	0.7	2
12	UV Light Emitter on Bulk Semipolar (11-22) GaN. , 2011, , .		0
13	Boosting Green GalnN/GaN Light-Emitting Diode Performance by a GalnN Underlying Layer. IEEE Transactions on Electron Devices, 2010, 57, 2639-2643.	3.0	16
14	Cyan and green light emitting diode on nonâ€polar <i>m</i> â€plane GaN bulk substrate. Physica Status Solidi C: Current Topics in Solid State Physics, 2010, 7, 2190-2192.	0.8	4
15	Wavelength-stable cyan and green light emitting diodes on nonpolar m-plane GaN bulk substrates. Applied Physics Letters, 2010, 96, .	3.3	59
16	Green LED development in polar and non-polar growth orientation. Proceedings of SPIE, 2009, , .	0.8	5